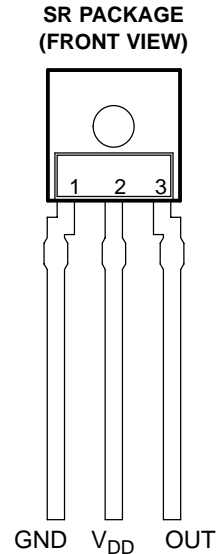


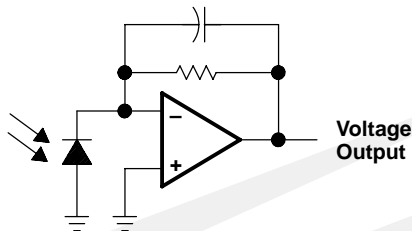
- Monolithic Silicon IC Containing Photodiode, Operational Amplifier, and Feedback Components
- Converts Light Intensity to Output Voltage
- High Irradiance Responsivity . . . Typically 60 mV/( $\mu\text{W}/\text{cm}^2$ ) at  $\lambda_p = 880 \text{ nm}$  (TSL253)
- High Bandwidth
- Compact 3-Leaded Clear Plastic Package
- Low Dark (Offset) Voltage . . . 10 mV Max At 25°C,  $V_{DD} = 5 \text{ V}$
- Single-Supply Operation
- Wide Supply-Voltage Range . . . 2.7 V to 5.5 V
- Low Supply Current . . . 600  $\mu\text{A}$  Typical at  $V_{DD} = 5 \text{ V}$



## Description

The TSL253 and TSL254 are light-to-voltage optical converters, each combining a 1-mm-square photodiode and a transimpedance amplifier (feedback resistor = 16 M $\Omega$ , and 1 M $\Omega$  respectively) on a single monolithic IC. Output voltage is directly proportional to the light intensity (irradiance) on the photodiode. These devices use silicon-gate CMOS technology that provides improved amplifier offset-voltage stability and low power consumption.

## Functional Block Diagram



## Terminal Functions

TERMINAL NAME	NO.	DESCRIPTION
GND	1	Ground (substrate). All voltages are referenced to GND.
OUT	3	Output voltage
V <sub>DD</sub>	2	Supply voltage

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## Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{DD}$ (see Note 1)	7 V
Output current, $I_O$	$\pm 10$ mA
Duration of short-circuit current at (or below) 25°C	5 s
Operating free-air temperature range, $T_A$	-25°C to 85°C
Storage temperature range, $T_{stg}$	-25°C to 85°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	240°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to GND.

## Recommended Operating Conditions

	MIN	MAX	UNIT
Supply voltage, $V_{DD}$	2.7	5.5	V
Operating free-air temperature, $T_A$	0	70	°C

## Electrical Characteristics at $V_{DD} = 5$ V, $T_A = 25^\circ\text{C}$ , $\lambda_p = 880$ nm, $R_L = 10$ k $\Omega$ (unless otherwise noted) (see Notes 2 and 3)

PARAMETER	TEST CONDITIONS	TSL253			TSL254			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
$V_D$ Dark voltage	$E_e = 0$			10			10	mV
$V_{OM}$ Maximum output voltage swing	$E_e = 2$ mW/cm <sup>2</sup>	3	3.5		3	3.5		V
$V_O$ Output voltage	$E_e = 35$ $\mu\text{W}/\text{cm}^2$	1.6	2	2.4				V
	$E_e = 595$ $\mu\text{W}/\text{cm}^2$				1.6	2	2.4	
$\alpha_{vo}$ Temperature coefficient of output voltage ( $V_O$ )	300 nm < $\lambda$ < 700 nm		-0.2			-0.2		%/ $^\circ\text{C}$
	$\lambda_p = 880$ nm		0.05			0.05		
$N_e$ Irradiance responsivity			60			3.5		mV/( $\mu\text{W}/\text{cm}^2$ )
Power supply rejection, dc			60			60		dB
Power supply rejection, ac	$f_{ac} = 1$ kHz		18			44		dB
$I_{DD}$ Supply current			0.6	1.5		0.6	1.5	mA

NOTES: 2. The input irradiance  $E_e$  is supplied by a GaAlAs infrared-emitting diode with  $\lambda_p = 880$  nm.

3. Irradiance responsivity is characterized over the range  $V_O = 0.05$  to 3 V.

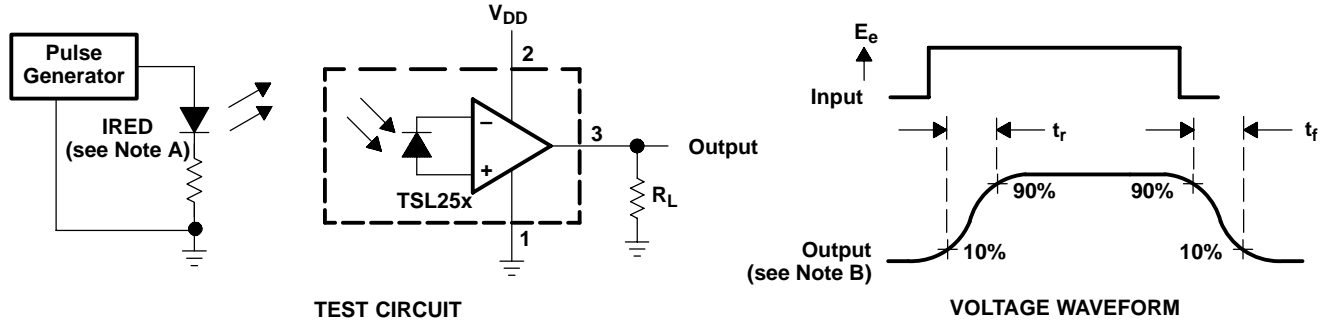
## Switching Characteristics at $T_A = 25^\circ\text{C}$ (see Figure 1)

PARAMETER	TEST CONDITIONS	TSL253			TSL254			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
$t_r$ Output pulse rise time	$V_{DD} = 5$ V, $\lambda_p = 880$ nm		7.5			2		$\mu\text{s}$
$t_f$ Output pulse fall time	$V_{DD} = 5$ V, $\lambda_p = 880$ nm		7.5			2		$\mu\text{s}$
$V_n$ Output noise voltage	$V_{DD} = 5$ V	$f = 100$ Hz		3		1.7		$\mu\text{V}/\sqrt{\text{Hz}}$
		$f = 1$ kHz		3		1		
		$f = 10$ kHz		6		1.3		

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**PARAMETER MEASUREMENT INFORMATION**



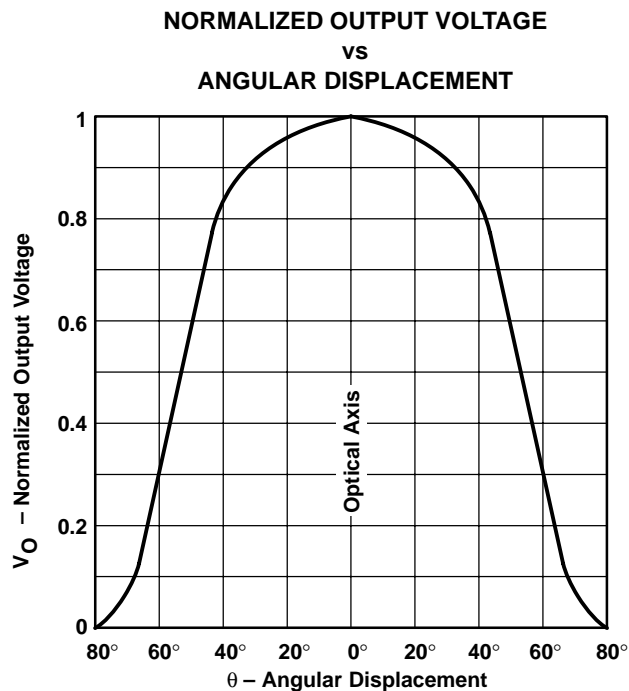
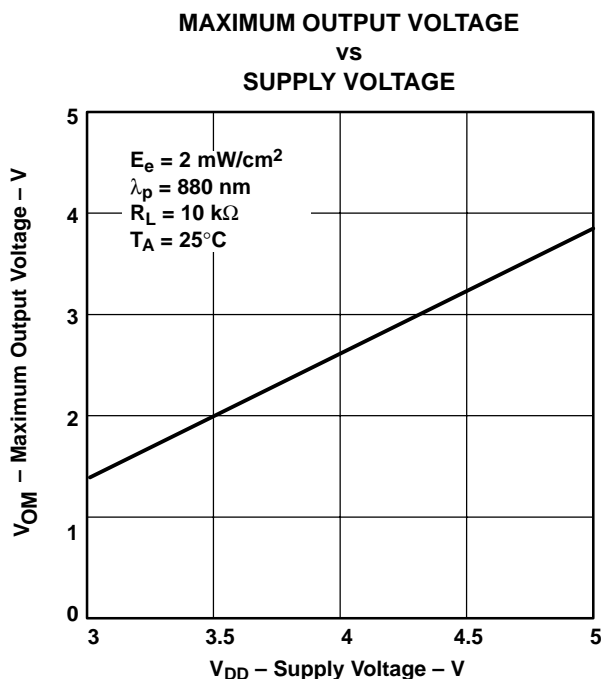
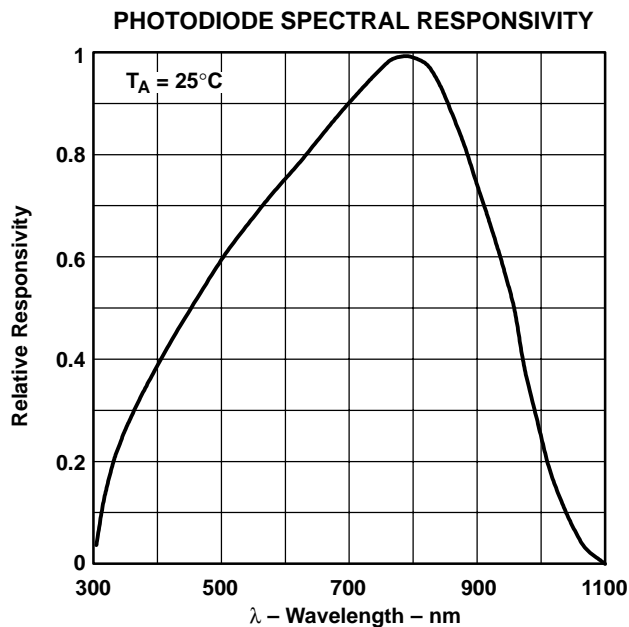
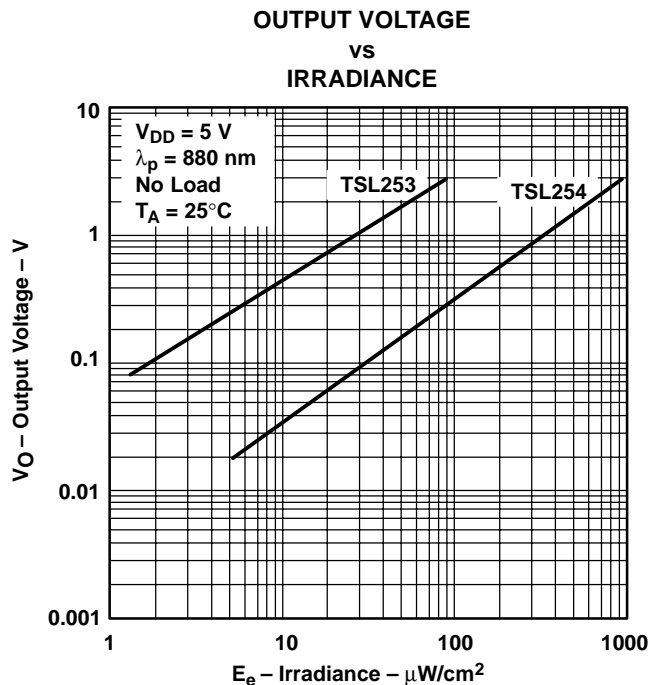
- NOTES: A. The input irradiance is supplied by a pulsed GaAlAs infrared-emitting diode with the following characteristics:  $\lambda_p = 880 \text{ nm}$ ,  $t_r < 1 \mu\text{s}$ ,  $t_f < 1 \mu\text{s}$ .
- B. The output waveform is monitored on an oscilloscope with the following characteristics:  $t_r < 100 \text{ ns}$ ,  $Z_i \geq 1 \text{ MHz}$ ,  $C_i \leq 20 \text{ pF}$ .

**Figure 1. Switching Times**

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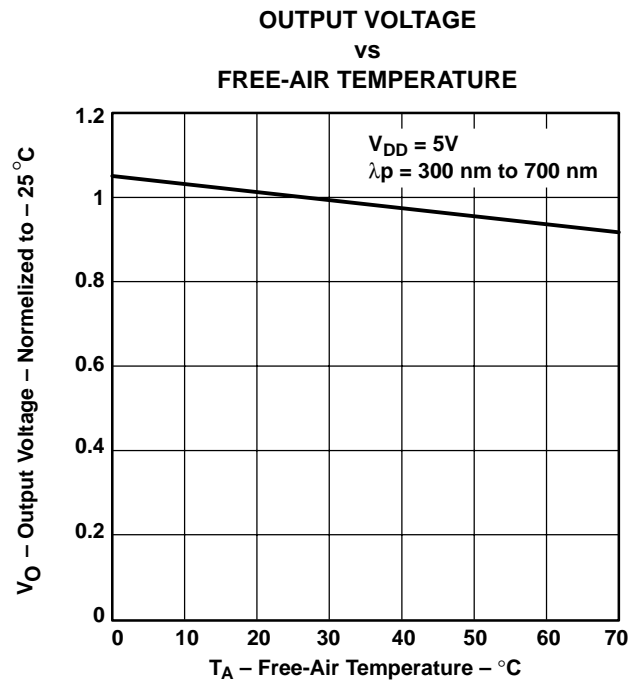
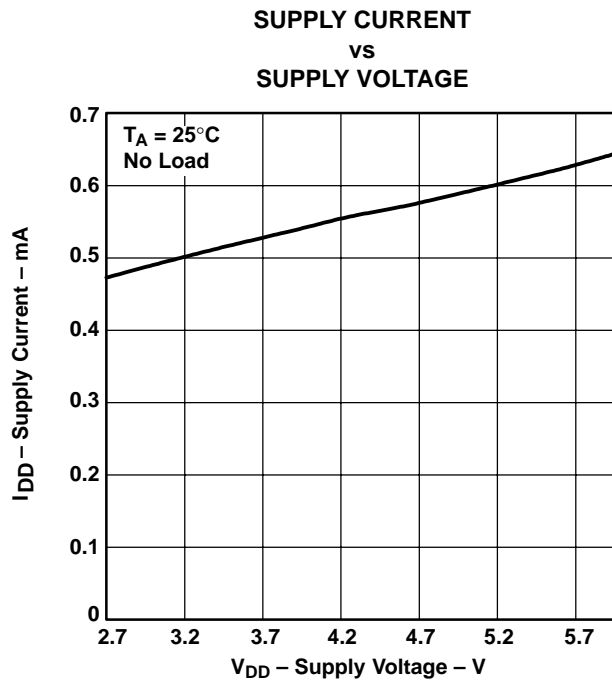
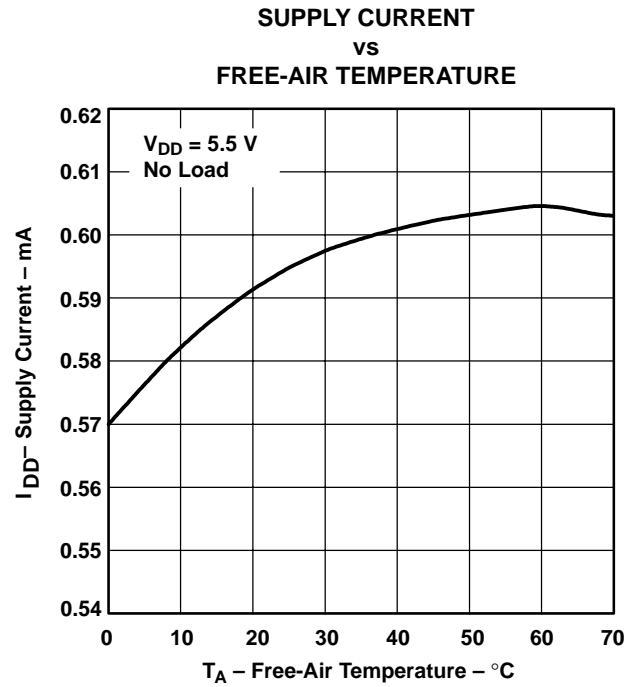
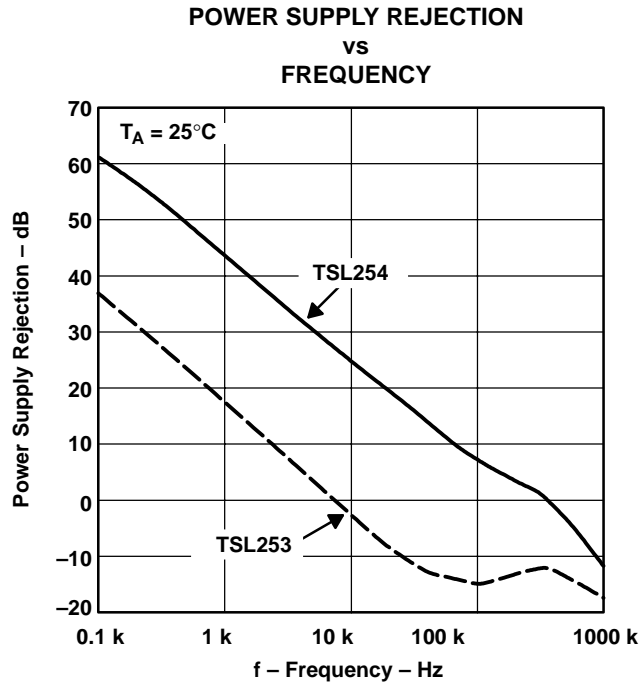
## TYPICAL CHARACTERISTICS



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**TYPICAL CHARACTERISTICS**



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## TYPICAL CHARACTERISTICS

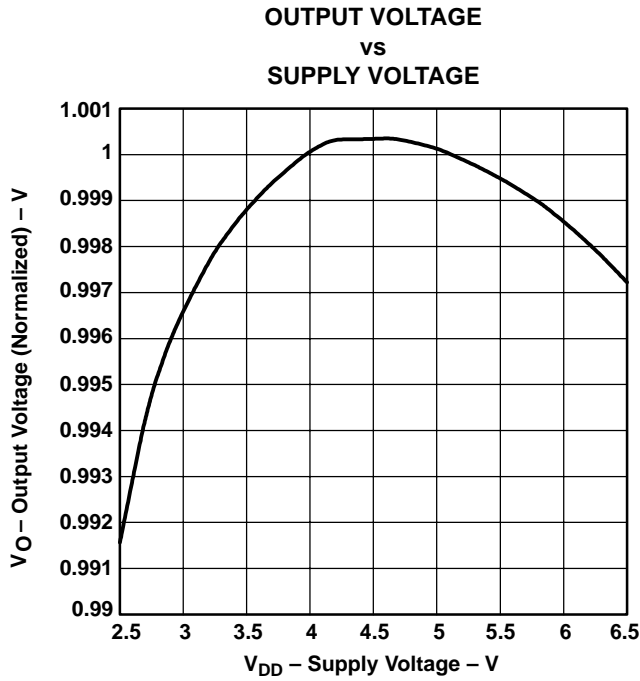


Figure 10

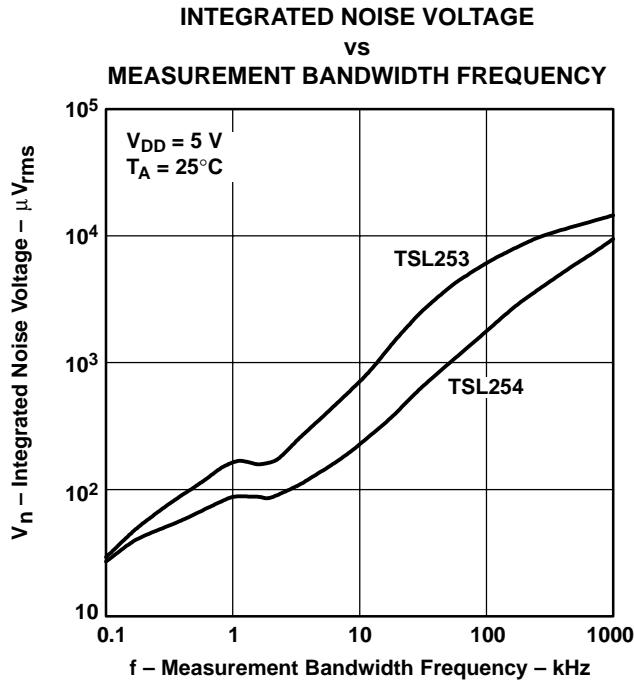
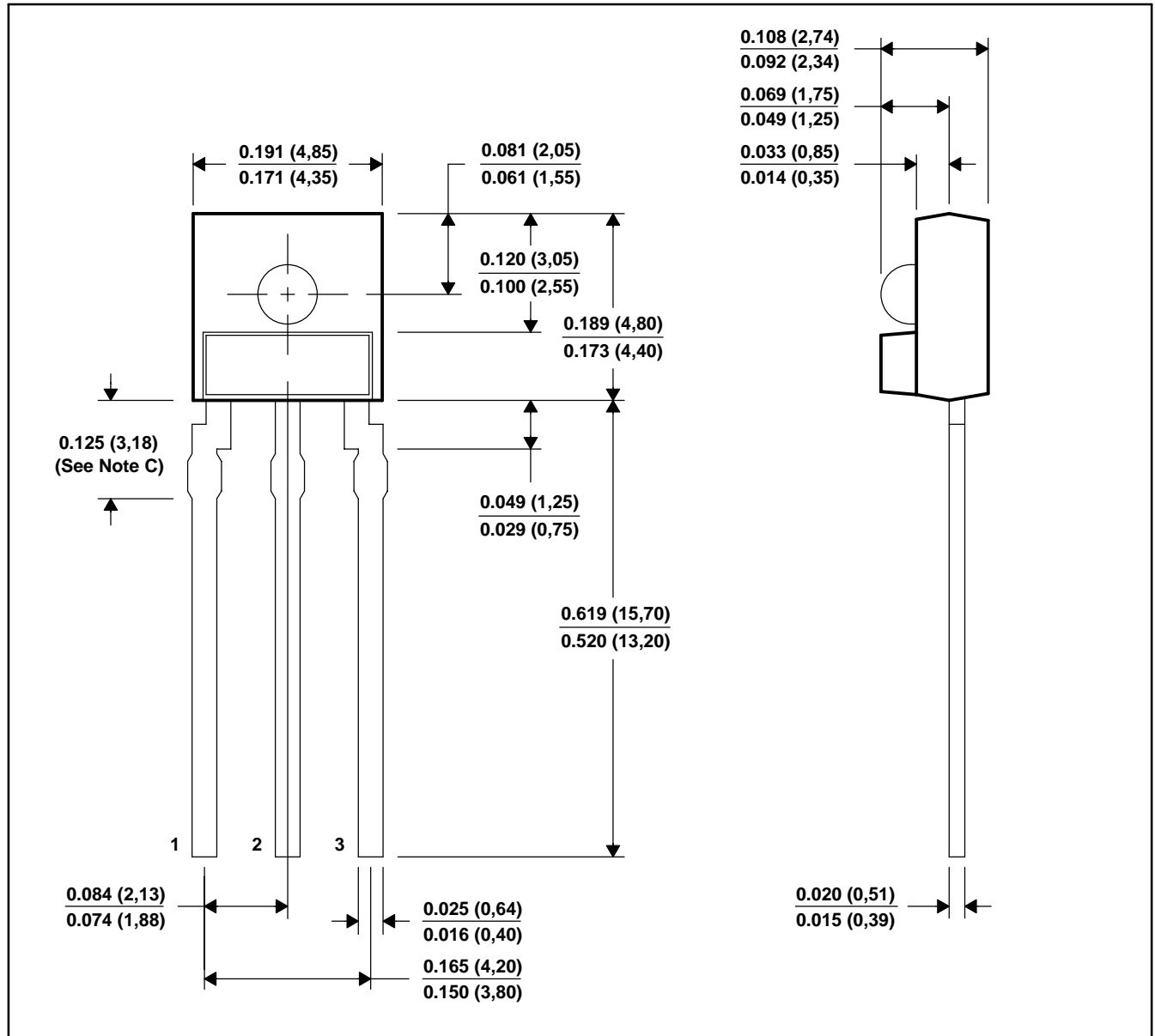


Figure 11

# TSL253, TSL254 PRECISION HIGH-SPEED LIGHT-TO-VOLTAGE CONVERTER

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## MECHANICAL DATA PLASTIC SINGLE-IN-LINE PACKAGE (OPTO)



- NOTES:
- All linear dimensions are in inches (millimeters).
  - This drawing is subject to change without notice.
  - Lead dimensions are not controlled within this area.
  - All dimensions apply before solder dip.
  - Package body is a clear nonfilled optically transparent material
  - Index of refraction of clear plastic is 1.55.

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